

### Vishay General Semiconductor

# **Dual Low-Voltage Trench MOS Barrier Schottky Rectifier**

Ultra Low  $V_F = 0.30 \text{ V}$  at  $I_F = 5.0 \text{ A}$ 



PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub>	2 x 15 A			
V <sub>RRM</sub>	45 V			
I <sub>FSM</sub>	200 A			
V <sub>F</sub> at I <sub>F</sub> = 15 A	0.39 V			
T <sub>J</sub> max.	150 °C			
Package	ITO-220AB			
Circuit configuration	Common cathode			

#### **FEATURES**

- Trench MOS Schottky technology
- · Low forward voltage drop, low power losses

• High efficiency operation

ROHS COMPLIANT HALOGEN

FREE

- Solder bath temperature 275 °C max. 10 s, per JESD 22-B106
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912"><u>www.vishay.com/doc?99912</u></a>

#### **TYPICAL APPLICATIONS**

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection.

#### **MECHANICAL DATA**

Case: ITO-220AB

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

**Terminals:** matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T <sub>A</sub> = 25 °C unless otherwise noted)					
PARAMETER		SYMBOL	VFT3045C	UNIT	
Maximum repetitive peak reverse voltage		$V_{RRM}$	45	V	
Maximum average forward rectified current (fig. 1)	per device	I <sub>F(AV)</sub>	30	Α	
	per diode		15		
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load		I <sub>FSM</sub>	200	А	
Isolation voltage from termal to heatsink t = 1 min		V <sub>AC</sub>	1500	V	
Operating junction and storage temperature range		T <sub>J</sub> , T <sub>STG</sub>	-40 to +150	°C	

<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS SYMBOL		SYMBOL	TYP.	MAX.	UNIT	
Instantaneous forward voltage per diode	I <sub>F</sub> = 5 A	T <sub>A</sub> = 25 °C	- V <sub>F</sub> <sup>(1)</sup>	0.42	-	V	
	I <sub>F</sub> = 7.5 A			0.44	-		
	I <sub>F</sub> = 15 A			0.49	0.57		
	I <sub>F</sub> = 5 A	T <sub>A</sub> = 125 °C		0.30	-		
	I <sub>F</sub> = 7.5 A			0.33	-		
	I <sub>F</sub> = 15 A			0.39	0.48		
Reverse current per diode	V - 45 V	$T_A = 25 ^{\circ}\text{C}$	I <sub>R</sub> <sup>(2)</sup>	-	2000	μΑ	
	V <sub>R</sub> = 45 V	T <sub>A</sub> = 125 °C		17	50	mA	

#### **Notes**

 $^{(1)}\,$  Pulse test: 300  $\mu s$  pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms



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THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)					
PARAMETER		SYMBOL	VFT3045C	UNIT	
Typical thermal resistance	per diode	- R <sub>θJC</sub>	6.0	°C/W	
	per device		4.0		

ORDERING INFORMATION (Example)							
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
ITO-220AB	VFT3045C-M3/4W	1.76	4W	50/tube	Tube		

### **RATINGS AND CHARACTERISTICS CURVES** ( $T_A = 25$ °C unless otherwise noted)

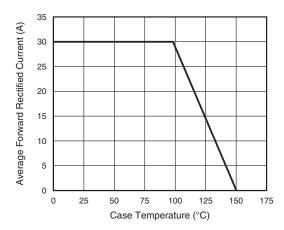


Fig. 1 - Maximum Forward Current Derating Curve

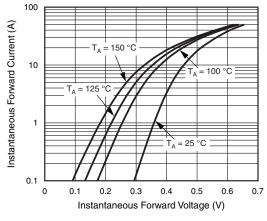


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

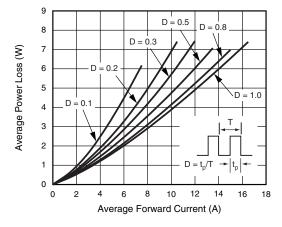


Fig. 2 - Forward Power Loss Characteristics Per Diode

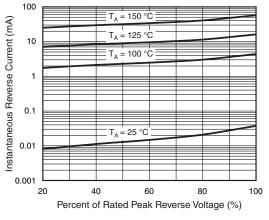


Fig. 4 - Typical Reverse Characteristics Per Diode



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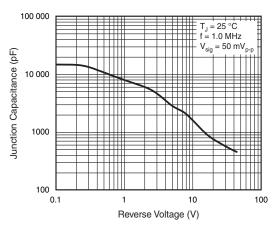


Fig. 5 - Typical Junction Capacitance Per Diode

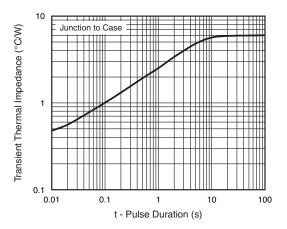
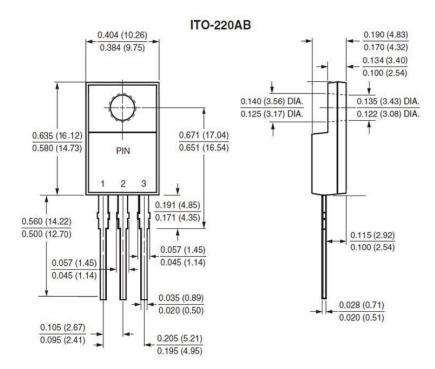


Fig. 6 - Typical Transient Thermal Impedance Per Diode

#### PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





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